

MC10E212, MC100E212

5V ECL 3-Bit Scannable Registered Address Driver

The MC10E/100E212 is a scannable registered ECL driver typically used as a fan-out memory address driver for ECL cache driving. In a VLSI array based CPU design, use of the E212 allows the user to conserve array output cell functionality and also output pins.

The input shift register is designed with control logic which greatly facilitates its use in boundary scan applications.

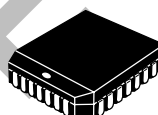
The 100 Series contains temperature compensation.

- Scannable Version E112 Driver
- 1025 ps Max. CLK to Output
- Dual Differential Outputs
- Master Reset
- PECL Mode Operating Range: $V_{CC}= 4.2\text{ V to }5.7\text{ V}$ with $V_{EE}= 0\text{ V}$
- NECL Mode Operating Range: $V_{CC}= 0\text{ V}$ with $V_{EE}= -4.2\text{ V to }-5.7\text{ V}$
- Internal Input Pulldown Resistors
- ESD Protection: $> 1\text{ KV HBM, } > 75\text{ V MM}$
- Meets or Exceeds JEDEC Spec EIA/JESD78 IC Latchup Test
- Moisture Sensitivity Level 1
For Additional Information, see Application Note AND8003/D
- Flammability Rating: UL-94 code V-0 @ 1/8", Oxygen Index 28 to 34
- Transistor Count = 259 devices



ON Semiconductor®

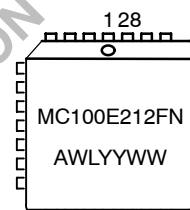
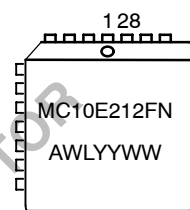
<http://onsemi.com>



PLCC-28
FN SUFFIX
CASE 776

A = Assembly Location
WL = Wafer Lot
YY = Year
WW = Work Week

MARKING DIAGRAMS

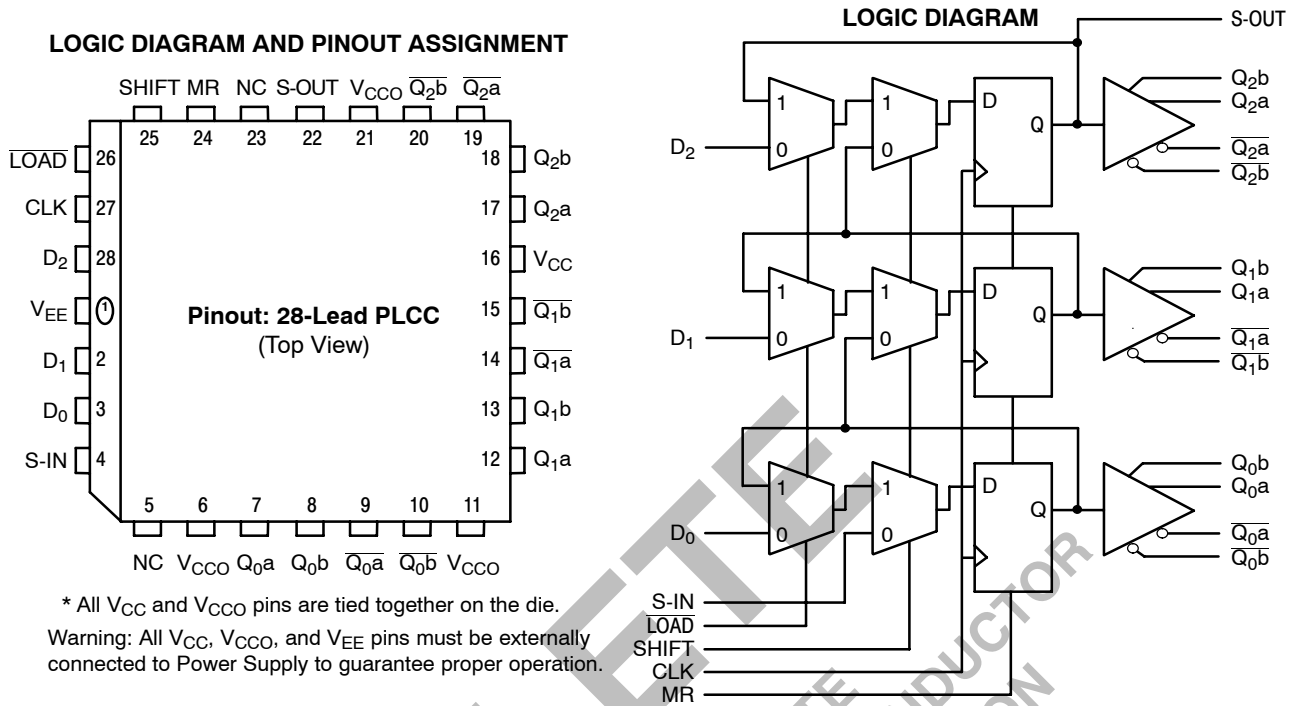


ORDERING INFORMATION

Device	Package	Shipping
MC10E212FN	PLCC-28	37 Units/Rail
MC10E212FNR2	PLCC-28	500 Units/Reel
MC100E212FN	PLCC-28	37 Units/Rail
MC100E212FNR2	PLCC-28	500 Units/Reel

MC10E212, MC100E212

5



PIN DESCRIPTION

PIN	FUNCTION
D ₀ - D ₂	ECL Data Inputs
S-IN	ECL Scan Input
LOAD	ECL LOAD/HOLD Control
SHIFT	ECL Scan Control
CLK	ECL Clock
MR	ECL Reset
S-OUT	ECL Scan Output
Q[0:2]a, Q[0:2]b	ECL True Outputs
\overline{Q} [0:2]a, \overline{Q} [0:2]b	ECL Inverting Outputs
V _{CC} , V _{CCO}	Positive Supply
V _{EE}	Negative Supply
NC	No Connect

FUNCTION TABLE

LOAD	SHIFT	MR	MODE
L	L	L	Load
H	L	L	Hold
X	H	L	Shift
X	X	H	Reset

MC10E212, MC100E212

MAXIMUM RATINGS (Note 1)

Symbol	Parameter	Condition 1	Condition 2	Rating	Units
V _{CC}	PECL Mode Power Supply	V _{EE} = 0 V		8	V
V _{EE}	NECL Mode Power Supply	V _{CC} = 0 V		-8	V
V _I	PECL Mode Input Voltage	V _{EE} = 0 V	V _I ≤ V _{CC}	6	V
	NECL Mode Input Voltage	V _{CC} = 0 V	V _I ≥ V _{EE}	-6	V
I _{out}	Output Current	Continuous Surge		50	mA
				100	
T _A	Operating Temperature Range			0 to +85	°C
T _{stg}	Storage Temperature Range			-65 to +150	°C
θ _{JA}	Thermal Resistance (Junction to Ambient)	0 LFPM	28 PLCC	63.5	°C/W
		500 LFPM	28 PLCC	43.5	
θ _{JC}	Thermal Resistance (Junction to Case)	std bd	28 PLCC	22 to 26	°C/W
V _{EE}	PECL Operating Range			4.2 to 5.7	V
	NECL Operating Range			-5.7 to -4.2	V
T _{sol}	Wave Solder	<2 to 3 sec @ 248°C		265	°C

1. Maximum Ratings are those values beyond which device damage may occur.

10E SERIES PECL DC CHARACTERISTICS V_{CCx}= 5.0 V; V_{EE}= 0.0 V (Note 1)

Symbol	Characteristic	0°C			25°C			85°C			Unit
		Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	
I _{EE}	Power Supply Current		80	96		80	96		80	96	mA
V _{OH}	Output HIGH Voltage (Note 2)	3980	4070	4160	4020	4105	4190	4090	4185	4280	mV
V _{OL}	Output LOW Voltage (Note 2)	3050	3210	3370	3050	3210	3370	3050	3227	3405	mV
V _{IH}	Input HIGH Voltage	3830	3995	4160	3870	4030	4190	3940	4110	4280	mV
V _{IL}	Input LOW Voltage	3050	3285	3520	3050	3285	3520	3050	3302	3555	mV
I _{IH}	Input HIGH Current			150			150			150	μA
I _{IL}	Input LOW Current	0.5	0.3		0.5	0.25		0.3	0.2		μA

NOTE: Devices are designed to meet the DC specifications shown in the above table, after thermal equilibrium has been established. The circuit is in a test socket or mounted on a printed circuit board and transverse air flow greater than 500 lpm is maintained.

- Input and output parameters vary 1:1 with V_{CC}. V_{EE} can vary +0.46 V / -0.06 V.
- Outputs are terminated through a 50 ohm resistor to V_{CC}-2 volts.

10E SERIES NECL DC CHARACTERISTICS V_{CCx}= 0.0 V; V_{EE}= -5.0 V (Note 1)

Symbol	Characteristic	0°C			25°C			85°C			Unit
		Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	
I _{EE}	Power Supply Current		80	96		80	96		80	96	mA
V _{OH}	Output HIGH Voltage (Note 2)	-1020	-930	-840	-980	-895	-810	-910	-815	-720	mV
V _{OL}	Output LOW Voltage (Note 2)	-1950	-1790	-1630	-1950	-1790	-1630	-1950	-1773	-1595	mV
V _{IH}	Input HIGH Voltage	-1170	-1005	-840	-1130	-970	-810	-1060	-890	-720	mV
V _{IL}	Input LOW Voltage	-1950	-1715	-1480	-1950	-1715	-1480	-1950	-1698	-1445	mV
I _{IH}	Input HIGH Current			150			150			150	μA
I _{IL}	Input LOW Current	0.5	0.3		0.5	0.065		0.3	0.2		μA

NOTE: Devices are designed to meet the DC specifications shown in the above table, after thermal equilibrium has been established. The circuit is in a test socket or mounted on a printed circuit board and transverse air flow greater than 500 lpm is maintained.

- Input and output parameters vary 1:1 with V_{CC}. V_{EE} can vary +0.46 V / -0.06 V.
- Outputs are terminated through a 50 ohm resistor to V_{CC}-2 volts.

MC10E212, MC100E212

100E SERIES PECL DC CHARACTERISTICS $V_{CCx}=5.0\text{ V}; V_{EE}=0.0\text{ V}$ (Note 1)

Symbol	Characteristic	0°C			25°C			85°C			Unit
		Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	
I_{EE}	Power Supply Current		80	96		80	96		92	110	mA
V_{OH}	Output HIGH Voltage (Note 2)	3975	4050	4120	3975	4050	4120	3975	4050	4120	mV
V_{OL}	Output LOW Voltage (Note 2)	3190	3295	3380	3190	3255	3380	3190	3260	3380	mV
V_{IH}	Input HIGH Voltage	3835	4050	4120	3835	4120	4120	3835	4120	4120	mV
V_{IL}	Input LOW Voltage	3190	3300	3525	3190	3525	3525	3190	3525	3525	mV
I_{IH}	Input HIGH Current			150			150			150	μA
I_{IL}	Input LOW Current	0.5	0.3		0.5	0.25		0.5	0.2		μA

NOTE: Devices are designed to meet the DC specifications shown in the above table, after thermal equilibrium has been established. The circuit is in a test socket or mounted on a printed circuit board and transverse air flow greater than 500 lpm is maintained.

1. Input and output parameters vary 1:1 with V_{CC} . V_{EE} can vary +0.46 V / -0.8 V.
2. Outputs are terminated through a 50 ohm resistor to $V_{CC}-2$ volts.

100E SERIES NECL DC CHARACTERISTICS $V_{CCx}=0.0\text{ V}; V_{EE}=-5.0\text{ V}$ (Note 1)

Symbol	Characteristic	0°C			25°C			85°C			Unit
		Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	
I_{EE}	Power Supply Current		80	96		80	96		92	110	mA
V_{OH}	Output HIGH Voltage (Note 2)	-1025	-950	-880	-1025	-950	-880	-1025	-950	-880	mV
V_{OL}	Output LOW Voltage (Note 2)	-1810	-1705	-1620	-1810	-1745	-1620	-1810	-1740	-1620	mV
V_{IH}	Input HIGH Voltage	-1165	-950	-880	-1165	-880	-880	-1165	-880	-880	mV
V_{IL}	Input LOW Voltage	-1810	-1700	-1475	-1810	-1475	-1475	-1810	-1475	-1475	mV
I_{IH}	Input HIGH Current			150			150			150	μA
I_{IL}	Input LOW Current	0.5	0.3		0.5	0.25		0.5	0.2		μA

NOTE: Devices are designed to meet the DC specifications shown in the above table, after thermal equilibrium has been established. The circuit is in a test socket or mounted on a printed circuit board and transverse air flow greater than 500 lpm is maintained.

1. Input and output parameters vary 1:1 with V_{CC} . V_{EE} can vary +0.46 V / -0.8 V.
2. Outputs are terminated through a 50 ohm resistor to $V_{CC}-2$ volts.

AC CHARACTERISTICS $V_{CCx}=5.0\text{ V}; V_{EE}=0.0\text{ V}$ or $V_{CCx}=0.0\text{ V}; V_{EE}=-5.0\text{ V}$ (Note 1)

Symbol	Characteristic	0°C			25°C			85°C			Unit
		Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	
f_{MAX}	Maximum Toggle Frequency		TBD			TBD			TBD		GHz
t_{PLH} t_{PHL}	Propagation Delay to Output										ps
	CLK	575	800	1025	575	800	1025	575	800	1025	
	MR	575	800	1025	575	800	1025	575	800	1025	
	CLK to S-OUT	575	800	1025	575	800	1025	575	800	1025	
t_s	Setup Time										ps
	D	175	25		175	25		175	25		
	SHIFT	150	-50		150	-50		150	-50		
	LOAD	225	50		225	50		225	50		
	S-IN	150	-50		150	-50		150	-50		
t_h	Hold Time										ps
	D	250	25		250	25		250	25		
	SHIFT	300	100		300	100		300	100		
	LOAD	225	0		225	0		225	0		
	S-IN	300	100		300	100		300	100		
t_{RR}	Reset Recovery	600	350		600	350		600	350		ps
t_{SKEW}	Within-Device Skew (Note 1.)		100			100			100		ps
t_{SKEW}	Within-Gate Skew (Note 2.)		50			50			50		ps
t_{JITTER}	Cycle-to-Cycle Jitter		TBD			TBD			TBD		ps
t_r t_f	Rise/Fall Times (20 - 80%)	275	425	650	275	425	650	275	425	650	ps

1. 10 Series: V_{EE} can vary +0.46 V / -0.06 V.
- 100 Series: V_{EE} can vary +0.46 V / -0.8 V.

1. Within-device skew is defined as identical transitions on similar paths through a device.

MC10E212, MC100E212

2. Within-gate skew is defined as the difference in delays between various outputs of a gate when driven from the same input.

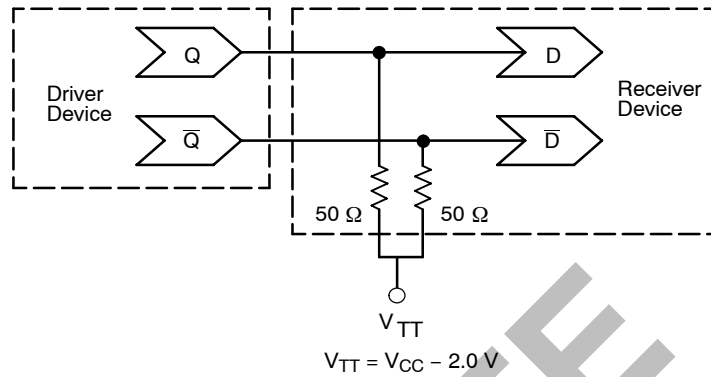


Figure 1. Typical Termination for Output Driver and Device Evaluation
(See Application Note AND8020 – Termination of ECL Logic Devices.)

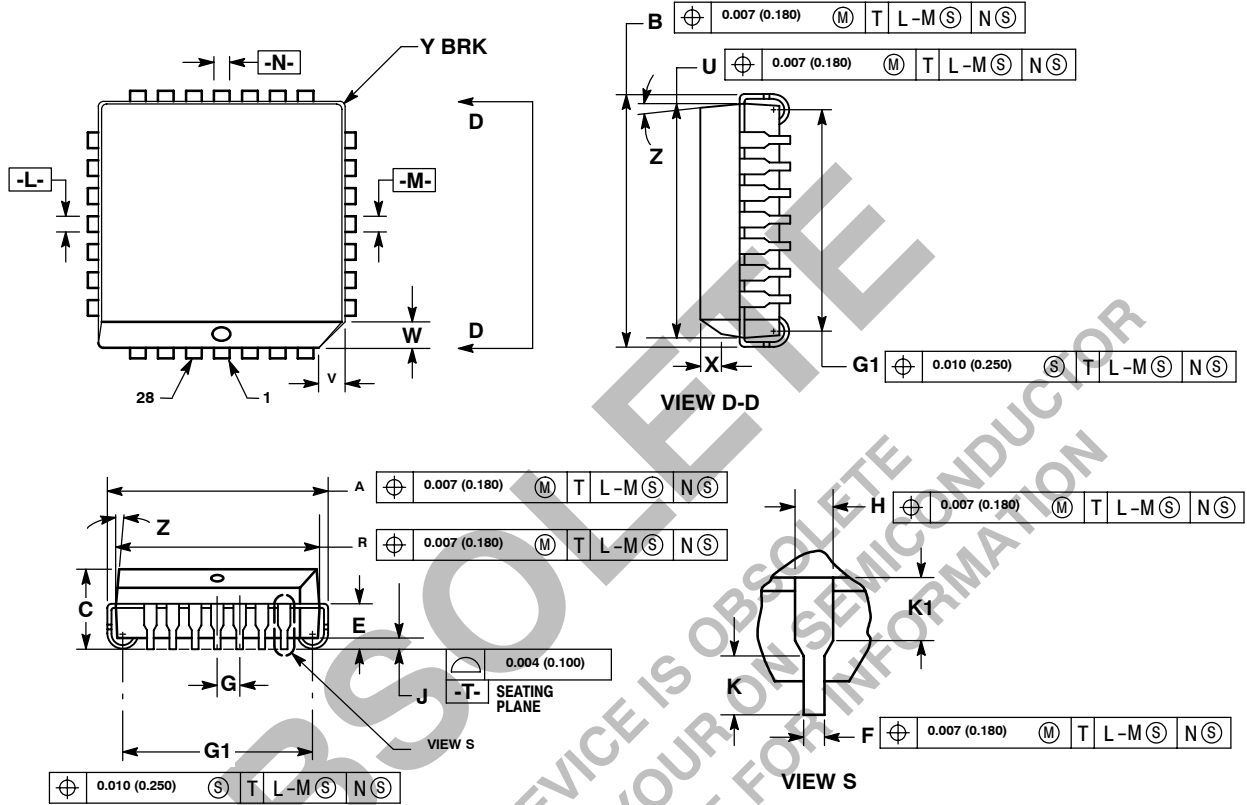
Resource Reference of Application Notes

- AN1404** – ECLinPS Circuit Performance at Non-Standard V_{IH} Levels
- AN1405** – ECL Clock Distribution Techniques
- AN1406** – Designing with PECL (ECL at +5.0 V)
- AN1503** – ECLinPS I/O SPICE Modeling Kit
- AN1504** – Metastability and the ECLinPS Family
- AN1568** – Interfacing Between LVDS and ECL
- AN1596** – ECLinPS Lite Translator ELT Family SPICE I/O Model Kit
- AN1650** – Using Wire-OR Ties in ECLinPS Designs
- AN1672** – The ECL Translator Guide
- AND8001** – Odd Number Counters Design
- AND8002** – Marking and Date Codes
- AND8020** – Termination of ECL Logic Devices

MC10E212, MC100E212

PACKAGE DIMENSIONS

PLCC-28
FN SUFFIX
PLASTIC PLCC PACKAGE
CASE 776-02
ISSUE E



NOTES:

- DATUMS -L-, -M-, AND -N- DETERMINED WHERE TOP OF LEAD SHOULDER EXITS PLASTIC BODY AT MOLD PARTING LINE.
- DIM G1, TRUE POSITION TO BE MEASURED AT DATUM -T-, SEATING PLANE.
- DIM R AND U DO NOT INCLUDE MOLD FLASH. ALLOWABLE MOLD FLASH IS 0.010 (0.250) PER SIDE.
- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- CONTROLLING DIMENSION: INCH.
- THE PACKAGE TOP MAY BE SMALLER THAN THE PACKAGE BOTTOM BY UP TO 0.012 (0.300). DIMENSIONS R AND U ARE DETERMINED AT THE OUTERMOST EXTREMES OF THE PLASTIC BODY EXCLUSIVE OF MOLD FLASH, TIE BAR BURRS, GATE BURRS AND INTERLEAD FLASH, BUT INCLUDING ANY MISMATCH BETWEEN THE TOP AND BOTTOM OF THE PLASTIC BODY.
- DIMENSION H DOES NOT INCLUDE DAMBAR PROTRUSION OR INTRUSION. THE DAMBAR PROTRUSION(S) SHALL NOT CAUSE THE H DIMENSION TO BE GREATER THAN 0.037 (0.940). THE DAMBAR INTRUSION(S) SHALL NOT CAUSE THE H DIMENSION TO BE SMALLER THAN 0.025 (0.635).

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.485	0.495	12.32	12.57
B	0.485	0.495	12.32	12.57
C	0.165	0.180	4.20	4.57
E	0.090	0.110	2.29	2.79
F	0.013	0.019	0.33	0.48
G	0.050 BSC		1.27 BSC	
H	0.026	0.032	0.66	0.81
J	0.020	—	0.51	—
K	0.025	—	0.64	—
R	0.450	0.456	11.43	11.58
U	0.450	0.456	11.43	11.58
V	0.042	0.048	1.07	1.21
W	0.042	0.048	1.07	1.21
X	0.042	0.056	1.07	1.42
Y	—	0.020	—	0.50
Z	2°	10°	2°	10°
G1	0.410	0.430	10.42	10.92
K1	0.040	—	1.02	—

OBSOLETE
THIS DEVICE IS OBSOLETE
PLEASE CONTACT YOUR ON SEMICONDUCTOR
REPRESENTATIVE FOR INFORMATION

ON Semiconductor and **ON** are registered trademarks of Semiconductor Components Industries, LLC (SCILLC). SCILLC reserves the right to make changes without further notice to any products herein. SCILLC makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does SCILLC assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in SCILLC data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. SCILLC does not convey any license under its patent rights nor the rights of others. SCILLC products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the SCILLC product could create a situation where personal injury or death may occur. Should Buyer purchase or use SCILLC products for any such unintended or unauthorized application, Buyer shall indemnify and hold SCILLC and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that SCILLC was negligent regarding the design or manufacture of the part. SCILLC is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor
P.O. Box 5163, Denver, Colorado 80217 USA
Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada
Fax: 303-675-2176 or 800-344-3867 Toll Free USA/Canada
Email: orderlit@onsemi.com

N. American Technical Support: 800-282-9855 Toll Free
USA/Canada
Europe, Middle East and Africa Technical Support:
Phone: 421 33 790 2910
Japan Customer Focus Center
Phone: 81-3-5773-3850

ON Semiconductor Website: www.onsemi.com
Order Literature: <http://www.onsemi.com/orderlit>

For additional information, please contact your local Sales Representative